Diode Semiconductor Device - Page 1 of 1



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| Inclosure Material:  |
|--|
| Glass  |
| Overall Length:  |
| 0.770 inches   |
| Terminal Length:   |
| 1.500 inches   |
| Overall Diameter:  |
| 0.400 inches   |
| Mounting Method:   |
| Terminal   |
| Features Provided:   |
| Hermetically sealed case   |
| Semiconductor Material:  |
| Silicon  |
| Voltage Rating In Volts Per Characteristic:                        |
| -400.0 emitter to base voltage, dc                                 |
| Current Rating Per Characteristic:                                 |
| 500.00 milliamperes forward current, average absolute              |
| Power Rating Per Characteristic:                                   |
| 500.0 milliwatts small-signal input power, common-collector preset |
| Maximum Operating Tempurature Per Measurement Point:               |
| 150.0 degrees celsius junction                                     |
| Terminal Type And Quantity:  |
| 2 uninsulated wire lead  |
| Shelf Life:  |
| N/a  |
| Unit Of Measure:   |
|  |
| Demilitarization:  |
| No   |
| Fiig:  |
| A110a0   |
|  |